Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-164-9742
Inclosure Material:
Metal
Overall Length:
0.355 inches
Overall Diameter:
0.275 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 emitter to base voltage, instantaneous
Current Rating Per Characteristic:
12.00 amperes average forward current averaged over a full 60-hz cycle
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0